

August 2006

FSUSB31

Low-Power 1-Port Hi-Speed USB 2.0 (480Mbps) Switch

Features

- Low On capacitance, 6.0pF (typical)
- Low On resistance, 6.5Ω (typical)
- Low power consumption (1µA maximum)
 - 10µA maximum ICCT over and expanded control voltage range (V_{IN} = 2.6V, V_{CC} = 4.3V)
- Wide -3dB bandwidth, > 720MHz
- 8K I/O to GND ESD protection
- Power OFF protection when V_{CC} = 0V, D+/D- pins can tolerate up to 4.3V
- Packaged in:
 - Pb-Free 8-lead MicroPak[™] (1.6 x 1.6mm)
 - Pb-Free 8-lead US-8

Applications

- Cell phone, PDA, Digital Camera, and Notebook
- LCD Monitor, TV, and Set-top Box

Related Application Notes

■ AN-6022 Using the FSUSB30/31 to Comply with USB 2.0 Fault Condition Requirements

Description

The FSUSB30 is a low-power, single-port, high-speed USB 2.0 switch. This part is configured as a single pole, single-throw switch and is optimized for switching or isolating a high-speed (480Mbps) source or a high-speed and full-speed (12Mbps) source. The FSUSB31 is compatible with the requirements of USB2.0 and features an extremely low On Capacitance (C_{ON}) of 6.0pF. The wide bandwidth of this device (>720MHz) exceeds the bandwidth needed to pass the third harmonic, resulting in signals with minimum edge and phase distortion. Superior channel-to-channel crosstalk minimizes interference.

The FSUSB31 contains special circuitry on the D+/D-pins that allows the device to withstand an over-voltage condition. This device is also designed to minimize current consumption even when the control voltage applied to the $\overline{\text{OE}}$ pin is lower than the supply voltage (V_{CC}). This feature is especially valuable for ultra-portable applications such as cell phones, allowing for direct interface with the general purpose I/Os of the baseband processor. Other applications include port isolation and switching in portable cell phones, PDAs, digital cameras, printers, and notebook computers.

Ordering Information

Part Number Package Pb-Free		Pb-Free	Package Description
FSUSB31K8X MAB08A Yes		Yes	8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide
FSUSB31L8X	MAC08A	Yes	8-Lead MicroPak, 1.6mm Wide

Pb-Free package per JEDEC J-STD-020B.

Application Diagram

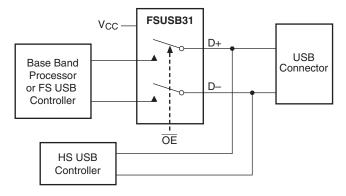


Figure 1. Typical Application Diagram

MicroPak™ is a trademark of Fairchild Semiconductor Corporation.

Connection Diagrams

Vcc 8 4 GND 1 2 3 +0

Figure 2. Pin Assignments for MicroPak

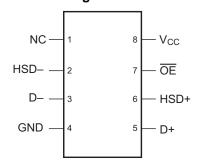


Figure 3. Pin Assignments for US8

Pin Descriptions

Pin Name	Description
ŌĒ	Bus Switch Enable
D+, D-, HSD+, HSD-	Data Ports
NC	No Connect

Truth Table

ŌĒ	Function
HIGH	Disconnect
LOW	D+, D- = HSD

Analog Symbol

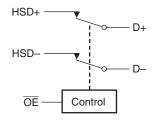


Figure 4. Analog Symbol

Absolute Maximum Ratings

The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table defines the conditions for actual device operation.

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply Voltage	-0.5V	4.6	V
V _S	DC Input Voltage ⁽¹⁾	-0.5V	4.6	V
V _{IN}	DC Switch Voltage ⁽¹⁾			
	HSD	-0.5V	V _{CC} +0.3	V
	D+, D-	-0.5	+4.6	V
I _{IK}	DC Input Diode Current	-50		mA
I _{OUT}	DC Output Current		50	mA
T _{STG}	Storage Temperature	-65	+150	°C
ESD	Human Body Model			
	All Pins		7.5	kV
	I/O to GND		8	kV

Recommended Operating Conditions⁽²⁾

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply Voltage	3.0	4.3	V
V _{IN}	Control Input Voltage	0V	V _{CC}	V
	Switch Input Voltage	0V	V _{CC}	V
T _A	Operating Temperature	-40	+85	°C

Notes:

- 1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed. DC switch voltage may never exceed 4.6V.
- 2. Control input must be held HIGH or LOW and it must not float.

DC Electrical Characteristics

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -	40°C to	+85°C	Unit	
Syllibol	Symbol Farameter Conditions		*CC (*)	Min. Typ. Max		Max.		
V _{IK}	Clamp Diode Voltage	I _{IN} = -18mA	3.0			-1.2	V	
V _{IH}	Input Voltage HIGH		3.0 to 3.6	1.3			V	
	Input voltage HIGH		4.3	1.7				
V _{IL}	Input Voltage LOW		3.0 to 3.6			0.5	V	
	Input voltage LOVV		4.3			0.7		
I _{IN}	Control Input Leakage	$V_{IN} = 0V$ to V_{CC}	4.3	-1.0		1.0	μΑ	
I _{OZ}	OFF State Leakage	$0 \le HSD \le V_{CC}$	4.3	-2.0		2.0	μΑ	
I _{OFF}	Power OFF Leakage Current (D+, D-)	$V_{IN} = 0.0V \text{ to } 4.3V, \\ V_{CC} = 0V$	0	-2.0		2.0	μА	
R _{ON}	Switch On Resistance ⁽³⁾	$V_{IN} = 0.4V, I_{ON} = -8mA$	3.0		6.5	10.0	Ω	
ΔR_{ON}	Delta R _{ON} ⁽⁴⁾	$V_{IN} = 0.4V, I_{ON} = -8mA$	3.0		0.35		Ω	
R _{ON} Flatness	R _{ON} Flatness ⁽³⁾	$V_{IN} = 0.0V - 1.0V,$ $I_{ON} = -8mA$	3.0		2.0		Ω	
i Guiesceni Subbiy Guireni I.		$V_{IN} = 0.0V \text{ or } V_{CC},$ $I_{OUT} = 0$	4.3			1.0	μА	
Ісст	Increase in I_{CC} Current per Control Voltage and V_{CC} Levels		4.3			10.0	μΑ	

Notes:

- 3. Measured by the voltage drop between Dn, HSD, and Dn pins at the indicated current through the switch. On Resistance is determined by the lower of the voltage on the two ports.
- 4. Guaranteed by characterization.

AC Electrical Characteristics

All typical values are for V_{CC} = 3.3V are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -	40°C to	+85°C	Unit	Figure	
Symbol	Faranteter	Conditions	*CC (*)	Min.	Тур.	Max.	Ollit	Number	
t _{ON}	Turn On Time, OE to Output	$\begin{aligned} &V_{\text{IN}} = 0.8 \text{V, R}_{\text{L}} = 50 \Omega, \\ &C_{\text{L}} = 5 \text{pF} \end{aligned}$	3.0 to 3.6		15.0	30.0	ns	Figure 12	
t _{OFF}	Turn OFF Time, OE to Output	$\begin{aligned} &V_{IN} = 0.8 \text{V, R}_{L} = 50 \Omega, \\ &C_{L} = 5 \text{pF} \end{aligned}$	3.0 to 3.6		12.0	25.0	ns	Figure 12	
t _{PD}	Propagation Delay ⁽⁴⁾	$R_L = 50\Omega$, $C_L = 5pF$	3.3		0.25		ns	Figure 10 Figure 11	
T _{BBM}	Break-Before-Make	$R_L = 50\Omega, C_L = 5pF, V_{IN} = 0.8V$	3.0 to 3.6	2.0		6.5	ns	Figure 13	
O _{IRR}	O_{IRR} OFF Isolation (Non-Adjacent) $R_T = 50\Omega$, $f = 240MI$		3.0 to 3.6		-35.0		dB	Figure 16	
Xtalk	alk Non-Adjacent Channel Crosstalk $R_T = 50\Omega$, $f = 240MHz$		3.0 to 3.6		-55.0		dB	Figure 17	
BW	-3dB Bandwidth	$R_T = 50\Omega$, $C_L = 0pF$	3.0 to 3.6		720		MHz	Figure 15	
DVV	Sub Banawidin	$R_T = 50\Omega$, $C_L = 5pF$	0.0 10 0.0		550		141112	i igule 13	

USB Hi-Speed Related AC Electrical Characteristics

Symbol	Parameter Conditions		V _{CC} (V)	T _A = -40°C to +85°C			Unit	Figure Number	
				Min.	Тур.	Max.		Number	
t _{SK(O)}	Channel-to-Channel Skew ⁽⁵⁾	C _L = 5pF	3.0 to 3.6		50.0		ps	Figure 10 Figure 14	
t _{SK(P)}	Skew of Opposite Transitions of the Same Output ⁽⁵⁾	C _L = 5pF	3.0 to 3.6		20.0		ps	Figure 10 Figure 14	
tJ	Total Jitter ⁽⁵⁾	$R_L = 50\Omega$, $C_L = 5pF$, $t_R = t_F = 500ps$ at 480 Mbps $(PRBS = 2^{15} - 1)$	3.0 to 3.6		200		ps		

Note:

5. Guaranteed by design.

Capacitance

Symbol	Parameter	Conditions	T _A = -	40°C to	Unit	Figure	
Symbol	Farameter	Conditions	Min.	Тур.	Max.		Number
C _{IN}	Control Pin Input Capacitance	V _{CC} = 0V		1.0		pF	Figure 19
C _{ON}	D1 _n , D2 _n , Dn ON Capacitance	$V_{CC} = 3.3, \overline{OE} = 0V$		6.0		pF	Figure 17
C _{OFF}	D1 _n , D2 _n OFF Capacitance	V_{CC} and $\overline{OE} = 3.3$		1.7		pF	Figure 19

Typical Characteristics

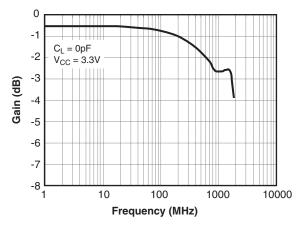


Figure 5. Gain vs. Frequency

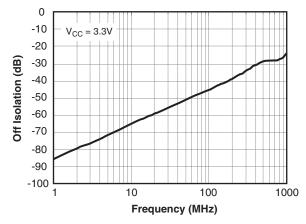


Figure 6. OFF Isolation

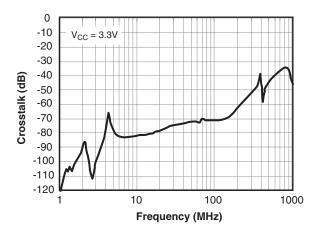


Figure 7. Crosstalk

Test Diagrams

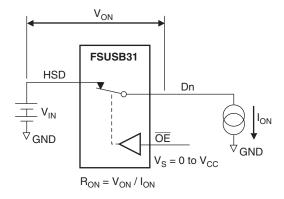
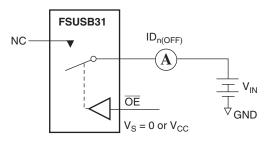
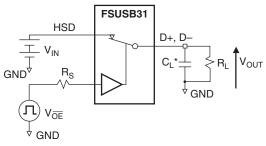


Figure 8. On Resistance



Each switch port is tested separately.

Figure 9. OFF Leakage



 R_L , R_S , and C_L are functions of the application environment (see AC Electrical tables for specific values).

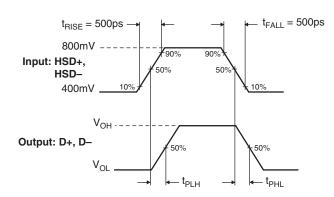


Figure 11. Switch Propagation Delay Waveforms (T_{PD})



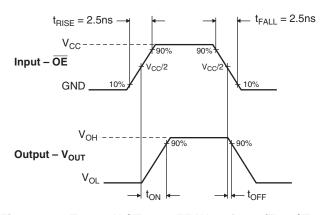


Figure 12. Turn ON / Turn OFF Waveform (T_{ON} / T_{OFF})

^{*}C_L includes test fixture and stray capacitance.

Test Diagrams (Continued)

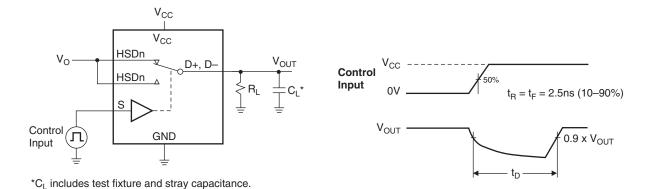


Figure 13. Break-Before-Make (T_{BBM})

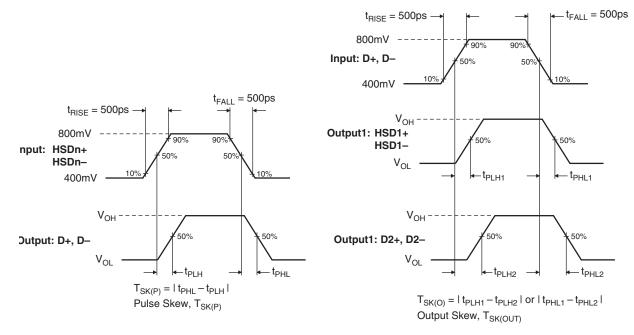


Figure 14. Switch Skew Tests

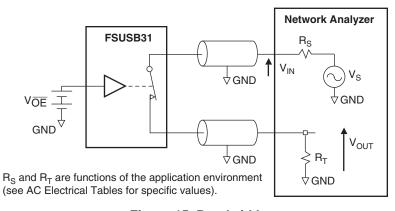


Figure 15. Bandwidth

Test Diagrams (Continued)

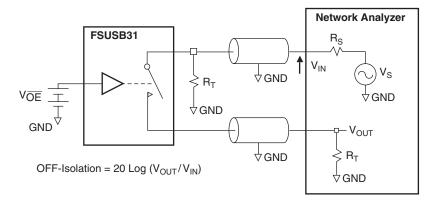


Figure 16. Channel OFF Isolation

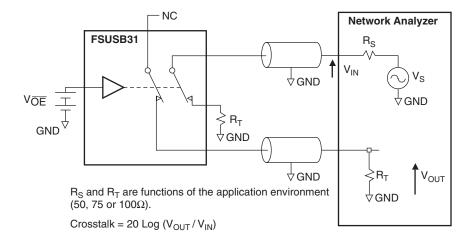


Figure 17. Non-Adjacent Channel-to-Channel Crosstalk

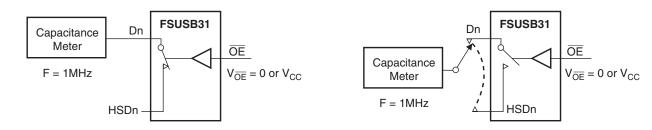


Figure 18. Channel ON Capacitance

Figure 19. Channel OFF Capacitance

Application Guidance: Meeting USB 2.0 Vbus Short Requirements

In section 7.1.1 of the USB 2.0 specification, it notes that USB devices must be able to withstand a Vbus short to D+ or D- when the USB devices is either powered off or powered on. The FSUSB31 can be successfully configured to meet both these requirements.

Power-Off Protection

For a Vbus short circuit, the switch is expected to withstand such a condition for at least 24 hours. The FSUSB31 has specially designed circuitry which prevents unintended signal bleed through as well as guaranteed system reliability during a power-down, overvoltage condition. The protection has been added to the common pins (D+, D-).

Power-On Protection

The USB 2.0 specification also notes that the USB device should be capable of withstanding a Vbus short during transmission of data. Fairchild recommends adding a 100Ω series resister between the switch VCC pin and supply rail to protect against this case. This modification works by limiting current flow back into the VCC rail during the over-voltage event so current remains within the safe operating range. In this application, the switch passes the full 5.25V input signal through to the selected output, while maintaining specified off isolation on the un-selected pins.

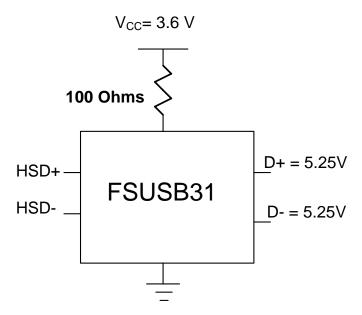


Figure 20. A 100 Ω resistor in series with the V_{CC} supply allows the FSUSB31 to withstand a Vbus short when powered up

For more information, see Applications Note AN-6022 Using the FSUSB30/FSUSB31 to Comply with USB 2.0 Fault Condition Requirements at www.fairchildsemi.com

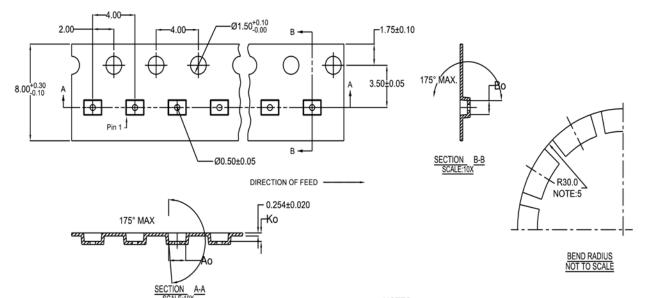
Tape and Reel Specification

Tape Format for MircoPak

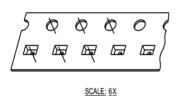
Package Designator	• • • • • • • • • • • • • • • • • • • •		Cavity Status	Cover Tape Status
	Leader (Start End)	125 (typ)	Empty	Sealed
L8X	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

Tape Dimension

Dimensions are in millimeters unless otherwise specified.



10	300056	2.30±0.05	1.78±0.05	0.68 ± 0.05
8	300038	1.78±0.05	1.78±0.05	0.68 ± 0.05
6	300033	1.60 ± 0.05	1.15±0.05	0.70 ± 0.05

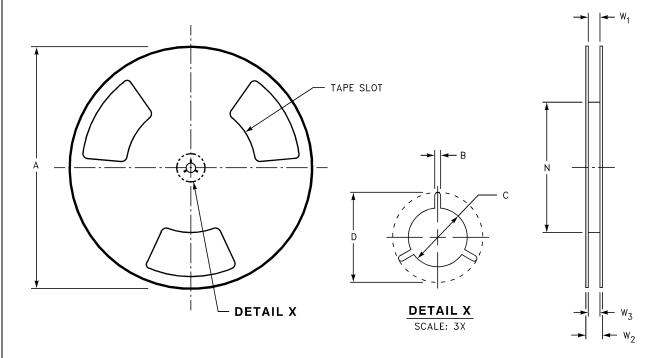


NOTES: UNLESS OTHERWISE SPECIFIED

- 1. ACCUMULATED 50 SPROCKETS, SPROCKET HOLE PITCH IS 200.00 ±0.30MM
- 2. NO INDICATED CORNER RADIUS IS 0.127MM
- 3. CAMBER NOT TO EXCEED 1MM IN 100MM
- 4. SMALLEST ALLOWABLE BENDING RADIUS
- 5. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED AS TRUE POSITION OF POCKET, NOT POCKET HOLE

Reel Dimension for MircoPak

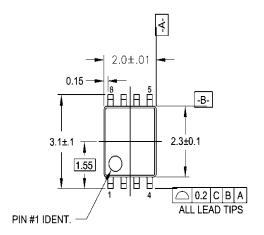
Dimensions are in inches (millimeters) unless otheriwise specified.

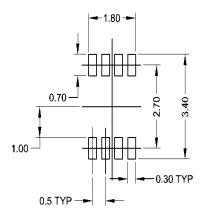


Tape Size	Α	В	С	D	N	W1	W2	W3
	7.0	0.059	0.512	0.795	2.165	0.331 + 0.059/-0.000	0.567	W1 + 0.078/-0.039
(8mm)	(177.8)	(1.50)	(13.00)	(20.20)	(55.00)	(8.40 + 1.50/-0.00)	(14.40)	(W1 + 2.00/-1.00)

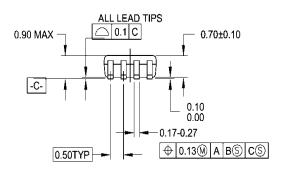
Physical Dimensions

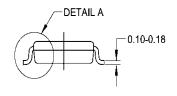
Dimensions are in millimeters unless otherwise noted.

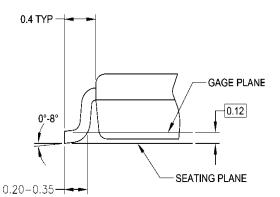




LAND PATTERN RECOMMENDATION







NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-187
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

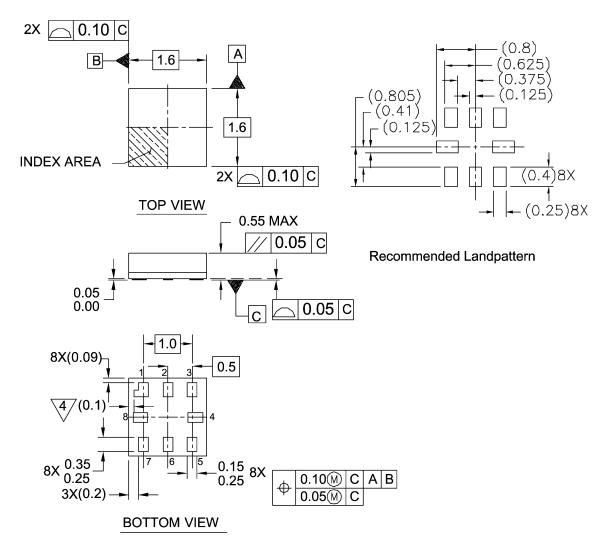
DETAIL A

MAB08AREVC

Figure 21. Pb-Free, 8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide

Physical Dimensions (Continued)

Dimensions are in millimeters unless otherwise noted.



Notes:

- 1. PACKAGE CONFORMS TO JEDEC MO-255 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y.14M-1994
- 4/PIN 1 FLAG, END OF PACKAGE OFFSET.

MAC08AREVC

Figure 22. Pb-Free, 8-Lead MicroPak, 1.6mm Wide

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Bottomless™	GTO™	OPTOLOGIC [®]	SPM™	
Build it Now™	HiSeC™	OPTOPLANAR™	Stealth™	
CoolFET™	I ² C™	PACMAN™	SuperFET™	
$CROSSVOLT^{TM}$	i-Lo™	POP™	SuperSOT™-3	
DOME™	ImpliedDisconnect™	Power247™	SuperSOT™-6	
EcoSPARK™	IntelliMAX™	PowerEdge™	SuperSOT™-8	
E ² CMOS™	ISOPLANAR™	PowerSaver™	SyncFET™	
EnSigna™	LittleFET™	PowerTrench [®]	TCM™	
FACT™	MICROCOUPLER™	QFET®	TinyBoost™	
FAST [®]	MicroFET™	QS™	TinyBuck™	
FASTr™	MicroPak™	QT Optoelectronics™	TinyPWM™	
FPS™	MICROWIRE™	Quiet Series™	TinyPower™	
FRFET™	MSX™	RapidConfigure™	TinyLogic [®]	
	MSXPro™	RapidConnect™	TINYOPTO™	
Across the board. Around the world.™		μSerDes™	TruTranslation™	
The Power Franchise [®]		ScalarPump™	UHC™	
Programmable Active Droop™				

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

UniFET™ UltraFET® VCX™ Wire™

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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